

Dr. D. NIRMAL

Professor & Head of the Department, Electronics and Communication Engineering, Karunya Institute of Technology and Sciences (Deemed to be University), Coimbatore, India - 641114. Office: +91-422 - 2614388; Mobile: +919789498810;

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ABOUT MYSELF

Serving Humanity through Teaching, Research, Collaboration and Leadership with passion. Has a good record with 15+ years of experience in Electronics and communication Engineering.

RESEARCH INTERESTS

Nanoelectronics,1D / 2D Materials, Graphene, Carbon nanotubes, GaN Technology, Nanoscale device design and modelling, Device and circuit simulation- GSI,Sensors.

EXPERIENCE

Professor, Electronics and communication Engineering, Karunya Institute of Technology and Sciences, Coimbatore, India , Nov 2020- Till Date

Associate Professor, Electronics and communication Engineering, Karunya Institute of Technology and Sciences, Coimbatore, India , July 2013- October 2020

Assistant Professor, Electronics and communication Engineering, Karunya Institute of Technology and Sciences, Coimbatore, India, June 2009- June 2013

Lecturer, Electronics and communication Engineering, Karunya Institute of Technology and Sciences, Coimbatore, India , June 2007- May 2009

RESEARCH PROFILES

1	Google Scholar Profile	https://scholar.google.co.in/citations?user=IdAzwA8AAAAJ&hl=en
2	Scopus Profile	https://www.scopus.com/authid/detail.uri?authorId=36816416200
3	LinkedIn Profile	https://in.linkedin.com/in/dr-d-nirmal-m-e-ph-d-smieee-lmiete-miste- 558a3963
4	Research Gate Profile	https://www.researchgate.net/profile/Dnirmal Phd
5	ORCID Profile	https://orcid.org/0000-0002-9751-2816
6	Publons - Web of Science Profile	https://publons.com/researcher/1407130/drnirmal-mephd/

PATENTS

1	A Multilayer GATE MOSFET for Reducing Short Channel Effect, Indian Patent Application No:20204109570— Granted.
2	A TRIBOELECTRIC NANOGENERATOR, Indian Patent Application No:202041027095 A – Filed and published in July 2020.
3	Biowaste Derived Carbon Electrode Super Capacitor, Indian Patent Application No: 20204 047605A – Filed and published in November 2020

RESEARCH PROJECTS ONGOING

#	¥	Tittle of the project	Funding Agency	Amount	Year
]	1	Design and Fabrication of Cascode Driver Circuit using GaNHEMT on Si for space applications	Indian Space Research Organization, Govt. of India	199 AA IAKN	2019- 2022
2		Design and Development of Gan HEMT for 18	Defense Research and Development Organization, Govt. of India		2022- 2025

RESEARCH PROJECTS COMPLETED

#	Tittle of the project	Funding Agency	Amount	Year
1	Modernization of RF laboratory with MIMO-SDR platform	All India Council for Technical Education	12.43 Lakh	2019- 2021
2	Modelling And Simulation of Tunnel FE1S for Low Power Applications	Department of Electronics and Information Technology, Govt. of India	25 lakh	2016- 2021
3	A compact modelling of Gan Based FP-HEM1 Device for High power microways Applications	Defense Research and Development Organization, Govt. of India	21.98 lakh	2017-2019
4	Development Of Bio-Compatible Cellulosic Printed Circuit Board For Flexible Electronics	Tamil Nadu State Council for Science And Technology	0.1 lakh	2017-2018
5	Growth of GaN Thin Film On Silicon Using PLD Method For High Electron Mobility Transistor	Karunya University	0.25 lakh	2017

SUMMARY OF INTERNATIONAL JOURNAL/ CONFERENCE/ BOOKPUBLICATIONS – (Given in Annexure)

2009 -	Publications	Publications 44	Publications 5	11
Year	International Journal	International Conference	National Conference	Book/Chapter

FELLOWSHIPS, AWARDS AND ACADEMIC ACHIEVEMENTS

1	Received IETE Smt. Manorama Rathore memorial award 2022 from IETE.
2	Karunya university Achievers Award 2019-2020 for obtaining funded project from AICTE
3	Karunya university Achievers Award 2018-2019 for obtaining funded project from ISRO
4	Young Achiever Award 2020 from Institution of Engineers, Coimbatore Chapter
5	Certificate of recognition for publishing in IEEE journal from Madras Section 2020
6	Received Best IEEE Volunteer Award 2020 from IEEE Madras Section
7	Received Young Scientist Award 2019 from the Academy of Sciences, Chennai
8	IEI Young Engineers Award- Electronics and Telecommunication Engineering- 2017.
9	Karunya university Achievers Award 2016-2017 for obtaining funded project from DRDO.
10	IEEE Madras Section Professional Achievement in the year 2016.
11	IEEE Electron Device Coimbatore Founding Chapter Chair (2015-2020).
12	Best Researcher Award from Karunya University in the year 2014.
13	Shir.P.K.Das Memorial Best Faculty Award in the Year 2013 by Nehru College of Educational and Charitable Trust.
14	Best Research Paper Award with high impact factor from Karunya University in the year 2012.
15	Received Shiksha Rattan Puraskar Award 2012 from Indian International friend ship Society.
16	Distinction in Master of Engineering (VLSI DESIGN)
17	Best Paper Award from Solid State Electronics Letters on January, 2021.

TEACHING INTERESTS

VLSI Design, CMOS VLSI Technology, Nano electronics, Solid State Device Modeling, Microelectronics,

Solid State Electronics, Electron Devices, Microwave and Optical Engineering.

RESEARCH GUIDANCE

Research guidance as supervisor	Completed	Ongoing
Doctor of Philosophy - PhD	8	8

EDUCATION

Ph.D., Faculty of Information and Communication Engineering, Highly Commended. (Specialization in Nano Device Modelling), Anna University, Chennai- 2012, India

MEng VLSI Design, 2007 [First Class with Distinction], Karunya University, India

BEng Electrical and Electronics, 2005, Anna University, Chennai, India

Post Graduate Diploma in Higher Education Indira Gandhi National Open University, 2015, India

POSITIONS OF RESPONSIBILITY

- **Teaching and Research**, VLSI Laboratory and Centre for research in Semiconductor Devices, Karunya University, Period July 2007 to Till Date.
- **Co-ordinator Post Graduate programme,** Place- Department of Electrical Technology (EEE,ECE,E&I and Media) Karunya University, June 2016- June 2018.
- **IEEE Student branch counsellor,** Karunya University, June 2016- till date.
- **Department Library In-charge**, Electronics and communication Engineering, Karunya University, June 2007 to 2013.
- Joint Chief Warden, Men's Hostel, Karunya University, January 2013- Till Date
- Warden, Men's Hostel, Karunya University, June 2007 to December 2010

PROFESSIONAL SOCIETY ACTIVITIES

- Life Member of ISTE(Indian Society for Technical Education)LM-56881
- Senior Member of IEEE (Institute of Electrical and Electronics Engineering)SM-92838928.
- Life Member of SSI(Semiconductor Society of India)
- Member of Institute of Engineers (India)M-1544705.
- Member of IETE (The Institution of Electronic and Telecommunication Engineers) M-215257
- Life Member of IAENG(International Association for engineers)

REVIEW ASSIGNMENTS FOR SCIENTIFIC JOURNALS/ SOCIETIES

- IEEE Electron Device Letters.
- International journal of Microelectronics (MJS) Elsevier.
- International Journal of Microelectronics Reliability Elsevier.
- International journal of Superlattices and Microstructures Elsevier.
- All IEEE Young Engineer's Humanitarian Challenge 2016- Jury member.

EDITORIAL MEMBER FOR JOURNAL

- Editor- Microelectronics Journal(Elsevier)
- Editorial Board member International journal of Electronics and communications (Elsevier)Till-January 2020.
- Guest Editor IEEE Trans on Nanotechnology.

INTERNATIONAL ADVISORY COMMITTEE:Several.

COLLABORATION:

- ISRO(Indian Space research organization), Government of India- Dr.Manish K Hooda
- DRDO(Defense research and Development Organization), Ministry of Defense- Dr. SubashChandar.
- Taiwan semiconductor research Institute Wen-KuanYeh, Director General.
- University of Sharjah, College of Engineering- Anwar Hasan Mohammed Jarndal.
- The University of Texas Rio Grande Valley (UTRGV)- Hasina F Huq PhD

TITLE: (Attached in Annexure)

- International conference resource person: 28
- National conference resource person: 2
- Workshop organized: 5
- International / national resource person: 47
- International courses/seminar attended: 9
- National courses / seminars attended: 27

RESEARCH CONSULTANCY

Consultancy work is carried out for DRDO in Technology Computer aided tool(TCAD) in 2017.

GRANT FETCHED

- Grand-in-aid for organizing **International conference on Devices**, **Circuits and Systems** from DRDO for the year 2012 with Rs 40,000.
- Grand-in-aid for organizing **National workshop on Electronics system Design and Manufacturing(ESDM)** from DIT for the year 2012 with Rs 30,000.

REFERENCE

Dr Manish Kumar Hooda डॉमनीषकुमारहुड्डा Head, Technology Development Division

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BRIEF BIO-SKETCH IN PARAGRAPH FORMAT

Dr. D. Nirmal is a Full Professor and Head of Electronics and communication Engineering, Karunya Institute of Technology and sciences. He specialized in VLSI Design after his Bachelor of Engineering and received his Ph.D in Information and Communication Engineering from Anna University. His research interests includes Nanoelectronics, GaN Technology, Device and Circuit Simulation – GSL, Sensors, HEMT, Beyond 5G, Nanoscale device design and modelling. He is a founding chair of IEEE Electron Device Society Coimbatore chapter and volunteered several committees in IEEE. He has funding project tune of 1.2 Cores from various agencies like DRDO(Defence Research and Development Organization), Ministry of Electronics and Information Technology,ISRO(Indian Space Research Organization) and AICTE(All India Council of Technical Education). He is a recipient of various awards namely IEI-Young Engineer award,IETE Smt. Manorama Rathore memorial award 2022 from IETE and Young Scientist Award 2019 from the Academy of Sciences.

Prof.Nirmal has made more than 150+ peer reviewed research publications and three patents to his credits. He is also a Senior IEEE member. He has delivered many Keynote talks, lectures in National and International Level conferences/Faculty Development programs.

ADDRESS FOR COMMUNICATION

3Carmel Quarters, Karunya Nagar, Coimbatore 641114 Tamil Nadu,India.Telephone:+914222614594; Mobile:+9194426 07016

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INTERNATIONAL JOURNALS PUBLICATIONS

thod of Journal Study (2022) 41) Atterials, sectronic
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witches 9367-9
9367-9 Veh, W. "(2021)
9367-9 Veh, W.

	"Investigation of RF and DC Performance of E-Mode Ino.8oGao.2oAs/InAs/Ino.8oGao.2oas Channel based DG-HEMTs for Future Submillimetre Wave and THz Applications" (2021) <i>IETE Journal of Research</i> , 67 (3), pp. 366-376. DOI: 10.1080/03772063.2018.1553641 (Impact Factor: 2.33)
77	Fletcher, A.S.A., D. Nirmal , Ajayan, J., Arivazhagan, L., Hamza, K.H., Murugapandiyan, P. "60 GHz Double Deck T-Gate AlN/GaN/AlGaN HEMT for V-Band Satellites" (2021) <i>Silicon</i> , DOI: 10.1007/s12633-021-01367-y(Impact Factor: 2.941)
76	Sathishkumar, M., Samuel, T.S.A., Vimala, P., D. Nirmal . "Performance Analysis of HfO2-SiO2 Stacked Oxide Quadruple Gate Tunnel Field Effect Transistor for Improved ON Current" (2021) <i>Silicon</i> , DOI: 10.1007/s12633-021-01394-9(Impact Factor: 2.941)
75	Sam, D.S.S., Moni, D.J., Paul, P.S., D. Nirmal . "A Novel Architecture for 10-bit 40MSPS Low Power Pipelined ADC Using a Simultaneous Capacitor and Op-amp Sharing Technique" (2021) <i>Silicon</i> , DOI: 10.1007/s12633-021-01241-x, (Impact Factor: 2.941)
74	Murugapandiyan, P., Hasan, M.T., Rajya Lakshmi, V., Wasim, M., Ajayan, J., Ramkumar, N., D. Nirmal . "Breakdown voltage enhancement of gate field plate Alo.295Gao.705N/GaN HEMTs" (2021) <i>International Journal of Electronics</i> , 108 (8), pp. 1273-1287, DOI: 10.1080/00207217.2020.1849819 (Impact Factor: 1.457)
73	Murugapandiyan, P., D. Nirmal , Tanvir Hasan, M., Varghese, A., Ajayan, J., Augustine Fletcher, A.S., Ramkumar, N., "Influence of AlN passivation on thermal performance of AlGaN/GaN high-electron mobility transistors on sapphire substrate: A simulation study" (2021) <i>Materials Science and Engineering B: Solid-State Materials for Advanced Technology</i> , 273, DOI: 10.1016/j.mseb.2021.115449, (Impact Factor: 3.407)
72	J.Ajayan D. Nirmal , R.Ramesh, SandipBhattacharyaa, ShubhamTayalaL.M.I, .Leo Joseph Laxman. Raju Thoutama D.Ajitha,power"A critical review of AlGaN/GaN-heterostructure based Schottky diode/HEMT hydrogen (H2) sensors for aerospace and industrial applications" 2021, <i>Measurements</i> , https://doi.org/10.1016/j.measurement.2021.110100 , (Impact Factor:5.131)
71	Sridevi, R., Pravin, J.C., Babu, A.R., D. Nirmal "Investigation of Quantum Confinement Effects on Molybdenum Disulfide (MoS2) Based Transistor Using Ritz Galerkin Finite Element Technique"(2021) <i>Silicon</i> DOI: 10.1007/s12633-021-01010-w, (Impact Factor:2.941)
70	Tayal, S., Ajayan, J., Joseph, L.M.I.L., Tarunkumar, J., D. Nirmal , Jena, B., Nandi, A."A Comprehensive Investigation of Vertically Stacked Silicon Nanosheet Field Effect Transistors: anAnalog/RF Perspective" (2021) <i>Silicon</i> , DOI: 10.1007/s12633-021-01128-x (Impact Factor:2.941)
69	Anvarifard, M.K., D. Nirmal "Creation of Step-Shaped Energy Band in a Novel Double-Gate GNRFET to Diminish Ambipolar Conduction" (2021), <i>IEEE Transactions on Electron Devices</i> , DOI: 10.1109/TED.2021.3069442, (Impact Factor:3.221)
68	Ajayan, J., D. Nirmal. , Tayal, S., Bhattacharya, S., Arivazhagan, L., Fletcher, A.S.A., Murugapandiyan, P., Ajitha, D., "Nanosheet field effect transistors-A next generation device to keep Moore's law alive: An intensive study" (2021), <i>Microelectronics Journal</i> , DOI: 10.1016/j.mejo.2021.105141, (Impact Factor:1.992)
67	Husna Hamza, K., D. Nirmal , Augustine Fletcher, A.S., Arivazhagan, L., Ajayan, J., Natarajan, R., "Highly scaled graded channel GaN HEMT with peak drain current of 2.48 A/mm" (2021) <i>AEU - International Journal of Electronics and Communications</i> , DOI: 10.1016/j.aeue.2021.153774 ((Impact Factor:3.169)
66	Ajayan, J., D. Nirmal , Mathew, R., Arivazhagan, L., Ajitha, D, "A critical review of design and fabrication challenges in InP HEMTs for future terahertz frequency applications" <i>Materials Science in Semiconductor Processing</i> , https://doi.org/10.1016/j.mssp.2021.105753, 2021, 128, 105753(Impact Factor:4.644)
65	Arivazhagan, L., Jarndal, A., D. Nirmal , "GaN HEMT on Si substrate with diamond heat spreader for high power applications" 2021, <i>Journal of Computational Electronics</i> . DOI: 10.1007/s10825-020-01646-8(Impact Factor:1.983)
64	Ravindran, A., D. Nirmal , Prajoon, P., Gracia Nirmala Rani, D, "Optical Grating Techniques for MEMS-Based Spectrometer-A Review".2021, <i>IEEE Sensors Journal</i> , 21(5), pp. 5645–5655, 9272803, DoI: 10.1109/JSEN.2020.3041196 (Impact Factor:4.325)

63	Murugapandiyan, P., D. Nirmal , Ajayan, J., Varghese, A., , "Investigation of Influence of SiN and SiO ₂ Passivation in Gate Field Plate Double Heterojunction Al _{0.3} Ga _{0.7} N/GaN/Al _{0.04} Ga _{0.96} N High Electron Mobility Transistors", 2021 ", <i>Silicon</i> , DOI: 10.1007/S12633-020-00503-4(2020). (Impact Factor:2.941)
2020	
62	Arivazhagan, L., D. Nirmal , Reddy, P. P. K., Ajayan, J., Godfrey, D., Prajoon, P., & Ray, A. (2020). "A Numerical Investigation of Heat Suppression in HEMT for Power Electronics Application" <i>Silicon</i> . doi:10.1007/s12633-020-00647-3 (Impact Factor:2.941)
61	Manikandan, M., D. Nirmal , Ajayan, J.,Prajoon, P., Dhivyasri, G., "Numerical investigation of traps and optical response in III-V nitride quantum LED, Optical and Quantum Electronics", 2020, 52(12), 513, <i>Optical and Quantum Electronics</i> (IF 1.842) Pub Date: 2020-11-22, DOI: 10.1007/s11082-020-02633-w, (Impact Factor: 2.794).
60	Arivazhagan, L., D. Nirmal , Chander, S.,Rajkumar, J.S., Bhagya Lakshmi, S., "Variable thermal resistance model of GaN-on-SiC with substrate scalability", <i>Journal of Computational Electronics</i> , 2020, 19(4), pp. 1546–1554. DoI: https://doi.org/10.1007/s10825-020-01561-y (Impact Factor:1.983).
59	Anwar Jarndal , L. Arivazhagan & D. Nirmal , "On the performance of GaN-on-Silicon, Silicon-Carbide, and Diamond substrates" <i>International Journal of RF and Microwave Computer-Aided Engineering</i> , 2020, 30(6), e22196, https://doi.org/10.1002/mmce.22196, (Impact Factor:1.987)
58	S. Manikandan1 , N. B. Balamurugan1 & D. Nirmal , "Analytical Model of Double Gate Stacked Oxide JunctionlessTransistor Considering Source/Drain Depletion Effects for CMOS LowPower Applications" <i>Silicon</i> ,DOI: https://doi.org/10.1007/s12633-019-00280-9 (Impact Factor:2.941)
57	D.Godfrey, D.Nirmal ,D. Godwinraj L. Arivazhagan,N.Mohankumar,J.Tzou and W.K.Yeh "Enhancement of DC and Breakdown Performance on Single to Multi-Step Gate FP Using GaN-HEMT for High Power Applications", <i>Silicon</i> ,DOI: 10.1007/s12633-020-00503-4(2020). (Impact Factor:2.941)
56	A.S. Augustine Fletcher, D. Nirmal , L. Arivazhagan and J. Ajayan , "An Intensive Study on Assorted Substrates Suitable for High JFOM AlGaN/GaN HEMT", <i>Silicon</i> ,DOI: 10.1007/s12633-020-00549-4 (2020). (Impact Factor:2.941)
55	J.Ajayan, D.Nirmal , P.Mohankumar, M.Saravanan, M.Jagadesh and L.Arivazhagan, "A review of photovoltaic performance of organic/inorganic solar cells for future renewable and sustainable energy technologies" <i>Superlattices and Microstructures</i> , https://doi.org/10.1016/j.spmi.2020. 106549, (2020) pp 1-53 (Impact Factor:2.658).
54	K.Husna Hamza and D. Nirmal, "A review of GaNHEMT broadband power amplifiers", <i>International Journal of Electronics and Communications (AEU)</i> , Vol 116, (2020) DOI:10.1016/j.aeue.2019.153040 (Impact Factor:3.169)
53	D.Godfrey, D.Nirmal , L. Arivazhagan, R.Ratheskannan, P.Issac Nelson, S.Rajesh, B.Vidhya and N.Mohankumar "A novel ZnPcnanorod derived piezoelectric nanogenerator for energy harvesting" <i>Physica E Low-Dimensional Systems and Nanostructures Vol.118 (2020)</i> (Impact Factor:3.369).
52	S.Angen, J. Grace jencyand D.Nirmal , "A wearable energy storage capacitor using graphene oxide and magnesuim oxide as electrodes" <i>Physica E Low-Dimensional Systems and Nanostructures</i> 115 (2020) (Impact Factor:3.369).
51	A.S. Augustine Fletcher, D. Nirmal , L. Arivazhagan, J. Ajayan and Varghese, A, "Enhancement of Johnson figure of merit in III-V HEMT combined with discrete field plate and AlGaN blocking layer", <i>International Journal of RF and Microwave Computer-Aided Engineering</i> ,vol 30, Issue 2(2020). (Impact Factor:1.987)
2019	
50	Rani, C.S.H., Bagan, K.B., D.Nirmal , and Roach, R.S., "Enhancement of Performance in TFET by Reducing High-K Dielectric Length and Drain Electrode Thickness" <i>Silicon</i> , doi:10.1007/s12633-019-00328-w (2019) (Impact Factor:2.941).
49	M.Manikandan, D.Nirmal , J.Ajayan, P.Mohankumar, P.Prajoon and L.Arivazhagan "A review of

applications", Superlattices and Microstructures 136 (2019). https://doi.org/ 10.1016/j.spmi. 2019.106294. (Impact Factor:2.658). J.Ajayan, D.Nirmal, Dheena Kurian,P.Mohankumar, L.Arivazhagan , A.S. Augustine Fletcher, T.D.Subash and M.Saravanan" Investigation of impact of gate underlap/overlap on the analog/RF performance of composite channel double gate MOSFETs" Journal of Vacuum Science & Technology B 37, 062201 (2019); https://doi.org/10.1116/1.5116199(Impact Factor:2.427). J.Ajayan, D.Nirmal, P.Mohankumar, Dheena Kurian,A.S. Augustine Fletcher ,LArivazhan and B.Santhoshkumar" GaAs metamorphic high electron mobility transistors for future deep space-biomedical-military and communication system applications: A review" Microelectronics journal, https://doi.org/10.1016/j.mejo. 2019.104604Vol 108, (2019) (Impact Factor:1.992). J.Ajayan, D.Nirmal, P.Mohankumar, and L.Arivazhan, "Investigation of Impact of Passivation Materials on the DC/RF Performances of InP-HEMTs for Terahertz Sensing and Imaging" Silicon, doi.org/10.1007/s12633-019-00226-1 (2019) pp 1-6 (Impact Factor:2.941). L. Arivazhagan , D. Nirmal, D.Godfrey, J. Ajayan , P.PrajoonA.S. Augustine Fletcher, A.Amir Anton Jone and J.S.Raj Kumar, "Improved RF and DC performance in AlGaN/GaNHEMT by P-type doping in GaN buffer for millimetre-wave applications", International Journal of Electronics and Communications (AEU), Vol 108, (2019) Pg 189-194. (Impact Factor:3.169) A.S. Augustine Fletcher, D. Nirmal, J. Ajayan and L. Arivazhagan, "Analysis of AlGaN/GaNHEMT using discrete field plate technique for high power and high frequency applications", International Journal of Electronics and Communications (AEU), Vol 99, (2019) Pg 325-330. (Impact Factor:3.169) Suresh Subramanian, B. Sundarambal and D. Nirmal, "Investigation on Simulation-Based Specific Absorption Rate in Ultra-Wideband Antenna for Breast Cancer Detection", IEEE Sensors Journal, Vol 18 No.24, 20 Dec 2018, (Impact Factor:4,925) D. Gracia, D. Nirmal and D. JackulineMoni, "Impact of Leakage Curr		
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BOOK PUBLICATION

2	BOOK Title: Semiconductor Devices and Technologies for Future Ultra Low Power Electronics Editors: D. Nirmal, J. Ajayan and Patrick Fay Publisher: CRC Press Taylor & Francis ISBN: 9781032061610
1	BOOK Title: Handbook for III-V High Electron Mobility Transistor Technologies Editors: D. Nirmal and J. Ajayan Publisher: CRC Press Taylor & Francis ISBN: 9781138625273

BOOK CHAPTER PUBLICATION

9	Chapter Title: Negative Capacitance Field Effect Transistors for Future Low Power Electronics Authors: D. Nirmal and J. Ajayan Publication Title: Low-Dimensional Nanoelectronic Devices Theoretical Analysis and Cutting-Edge Research Publisher: CRC Press ISBN: 9781774638668
8	Chapter Title: Phosphorene based Intelligent Nanosensor for Wearable Electronics Applications Authors: R.Ramesh, Arkaprava Bhattacharyya, Adhithan Pon, D. Nirmal, J. Ajayan Publication Title: Handbook of Nanomaterials for Sensing Applications Publisher: Elsevier ISBN: 9780128207833
7	Chapter Title: III-V Nanoscale Quantum Well Field Effect Transistors for Future High Performance and Low Power Logic Applications Authors: D. Nirmal and J. Ajayan Publication Title: Nanoscale VLSI Devices, Circuits and Applications Publisher: Springer

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6	Chapter Title: III-V Compound Semiconductor Transistors-From Planar to Nanowire Structures Authors: D. Nirmal and J. Ajayan Publication Title: VLSI and Post-CMOS Devices, Circuits and Modelling Publisher: IET Digital Library ISBN: 1785618199, 9781785618192.
5	Chapter Title: Impact of Semiconductor Materials and Architecture Design on TFET Device Performance Authors: M. Saravanan, Eswaran Parthasarathy, J. Ajayan, D. Nirmal Publication Title: Emerging Low-Power Semiconductor Devices Publisher: CRC ISBN: 9781032147291
4	Chapter Title: Performance Analysis of Dual Metal Double Gate Tunnel-FETs for Ultralow Power Applications Authors: D. Gracia and D. Nirmal Publication Title: Nanoelectronic Materials and Devices. Publisher: Springer ISBN: 978-981-10-7190-4
3	Chapter Title: InP-Based High-Electron-Mobility Transistors for High-Frequency Applications Authors: D. Nirmal and J. Ajayan Publication Title: Nanoelectronics Devices, Circuits and Systems Publisher: Elsevier ISBN: 9780128133538
2	Chapter Title: Modeling of Double gate MOSFETs Authors: D. Nirmal and J. Ajayan Publication Title: Nanoscale Devices Physics Modeling and their Application Publisher: CRC Press Taylor & Francis ISBN: 9781138060340
1	Chapter Title: A Fundamental Overview of High Electron Mobility Transistor and its Applications Authors: D. Nirmal and J. Ajayan Publication Title: Nanoscale Devices Physics Modeling and their Application Publisher: CRC Press Taylor & Francis ISBN: 9781138060340

INTERNATIONAL CONFERENCE RESOURCE PERSON

28	Technical Reviewer for the manuscripts submitted for the IEEE Madras Section International Conference 2021 (MASCON2021) held at Hotel Le-Royal Meridien, Chennai, Tamil Nadu, India during 27th-28th August 2021.
27	Session Chair in the "2 nd International conference on VLSI Devices, Circuits and Systems" held in Meghnad saha Institute of Technology Kolkata, India 18 th and 19 th July 2020
26	Sharing in the " Virtual Conference Organizers' Panel " held in IEEE Bangladesh Section,Bangladesh1 st and 2 nd , July 2020
25	Session Chair in the " IEEE Sponsored 4 th International conference on Communication and Electronic systems " held in PPG Institute of Technology, India 17th, July 2019
24	Session Chair in the 2019 International Conference on Computer Communication and Informatics (ICCCI 2019) Organized by Sri Shakthi Institute of Engineering and Technology – CoimbatoreIndia on 23 th -25 th January 2019.
23	Session Chair in the "3 rd IEEE International conference on Communication and Electronic systems" held in PPG Institute of TechnologyIndia 15 th and 16 th October 2018.
22	Session Chair in the 2018 International Conference on Computer Communication and Informatics (ICCCI 2017) Organized by Sri Shakthi Institute of Engineering and Technology – Coimbatore, India on 5 th January 2018.
21	Session Chair in the " IEEE Sponsored 2nd International conference on

	Communication and Electronic systems " held in PPG Institute of Technology, India 19 th October 2017.
20	Session Chair in the " IEEE Sponsored International conference on Signal processing and communication" held in Karunya University, India 28th July 2017.
19	Session Chair in the "IEEE Sponsored International conference on Innovations in Electrical ElectronicsInstrumentation and Media Technology" held in Karunya University, India 4 th February 2017.
18	Session Chair in the IEEE Sponsored International conference on Inventive systems and Control Organized by JCT College of Engineering and technology, India on 19 th January 2017.
17	Session Chair in the 2017 International Conference on Computer Communication and Informatics (ICCCI 2017) Organized by SreeShakthi Institute of Engineering and Technology - Coimbatore India on 7 th January 2017.
16	Session Chair in the IEEE International Conference on Communication and Electronics Systems (ICCES 2016) Organized by PPG Institute of Technology – Coimbatore, India on 21 st October 2016.
15	Session Chair in the IEEE International Conference on Inventive Computation Technologies (ICICT 2016) Organized by RVS Technical Campus- Coimbatore, India on 26 th to 27 th August 2016.
14	Session Chair in the IEEE EDS and IETE sponsored 3rd International Conference on Devices, Circuits and Systems Organized by Karunya University, India on 3 rd to 5 th March 2016.
13	Session Chair in the IEEE sponsored International conference on Electronics and Communication Systems Organized by Karpagam College of Engineering, India on 25 th February 2016.
12	Session Chair in the International conference on Systems Science Control Communication Engineering and Technology Organized by Karpagam Institute of Technology, India on 10 th August 2015.
11	Session Chair in the International conference on Networks Electronics Communication and Control Organized by Cape Institute of Technology, India on 5 th and 6 th March 2015.
10	Session Chair in the IEEE 9 th International conference on Intelligent Systems and Control" Organized by Karpagam college of Engineering, India on 9 th and 10 th January 2015.
9	Session Chair in the IEEE SSCS Sponsored Conference On "Solid State Circuits" Organized by Saint Gits college of Engineering, India on 29 th August 2014.
8	I have served as a organizing secretary of 2nd International conference on Devices , Circuits and Systems sponsored by IEEE EDS INDIA and IETE INDIA March 6 th to 8 th 2014.
7	Session Chair in the International Conference Innovations in InformationEmbedded and Communication systems Organized by Karpagam college of Engineering, India on 13 th and 14 th of March 2014.
6	Session Chair in the I nternational Conference on Devices circuits and systems Organized by Karunya University, India on 6th to 8th March2014.
5	Session Chair in the International Conference on Electronics and Communication Systems Organized by Karpagam college of Engineering, India on 13 th and 14 th of February 2014.
4	I have served as a organizing secretary of International conference on DevicesCircuits and Systems sponsored by IEEE EDS INDIA and IETEINDIA March 15 th and 16 th 2012.
3	Session Chair in the International Conference on Innovations in Intelligent InstrumentationOptimization and Signal Organized by Karunya UniversityIndia on 1st March 2013.
2	Session Chair in the IEEE International Multi Automation Computing Control Communication and Compressed Sensing Organized by St. Joseph's College of Engineering and Technology, India on 22 th and 23 th March 2013.
1	Session Chair in the 2013 IEEE International Conference on Emerging Trends in Computing, India on 25 th and 26 th March 2013 Communication and Nanotechnology Organized by Infant Jesus College of Engineering

NATIONAL CONFERENCE RESOURCE PERSON

2	Session Chair in the National Conference on Innovations in future communication Technologies , (NCIFCT'17) Organized by Karunya university, India on 30 th March 2017
1	Session Chair in the Fourth National Conference on Communication , Computation , Control and Automation , CCCA 2014 Organized by Sri Ramakrishna Institute of Technology, India on 28 th and 29 th March 2014.

WORKSHOP ORGANIZED

***************************************	WORKSHOT ORGENIEED	
5	Organized One day workshop on "2 nd National Workshop on Semiconductor device modeling and applications" in Karunya University11 th January 2017.	
4	Organized One day IEEE ED Coimbatore Chapter sponsored workshop "National Workshop on Semiconductor device modeling and applications" in Karunya University9 th October 2015.	
3	Organized One day IEEE ED Coimbatore Chapter sponsored workshop "National Workshop on semiconductor memories" in 18 th September 2015.Karunya University	
2	Organized two day workshop on "National Workshop on circuit simulation on TANNER EDA Tool" in Karunya25 th and 26 th March 2011. University	
1	Organized one day DIT sponsored workshop on " Electronic System Design Manufacturing " in Karunya University14 th October 2012.	

INTERNATIONAL / NATIONAL RESOURCE PERSON

62	Resource Person for the lecture on 'Memory Core and Memory Peripheral Security, in the FDP conducted on January19,2022 at PSNA College of Technology,
	Dindigul
<i>C</i> -	Resource Person for the lecture on 'Electronics System Design and Manufacturing in Technology Node Perspective and Blended Research Outputs
61	Metrics', conducted on January 20, 2022 at United Institute of Technology, Coimbatore.
60	Exceptional contribution as Primary Evaluator in the Toycathon 2021 conducted by Ministry of Education Innovation Cell.
59	Resource Person for the workshop on 'NanoMaterials & Devices: Physics and Applications', conducted on March 11th and 12th at VIT Chennai.
58	Keynote talk on "Sustainable Electronic system in current trends" at the 6th International Conference on Inventive Computation Technologies(ICICT-2021) organized by RVS Technical Campus, Coimbatore, Tamilnadu, India, on 21.01.2021.
57	Resource Person in the 2 Day Online Faculty Development Program on Future Perspective of Semiconductor Devices organized by Kalasalingam Academy of Research and Education on 22-24 June 2021
56	Keynote talk in the 2 nd International Conference on Electronics and Sustainable Communication Systems held at Hindustan Institute of Technology and Sciences,
	Coimbatore, India on 04 August 2021
55	Coimbatore, India on 04 August 2021 Resource Person in the 2 Day National Level workshop on Modeling of semiconductor Quantum Devices for a Sustainable Energy System using TCAD " organized by Kalasalingam Academy of Research and Education on 08 January 2021
55 54	Resource Person in the 2 Day National Level workshop on Modeling of semiconductor Quantum Devices for a Sustainable Energy System using TCAD " organized by

	Approach for Cutting Edge Program " in Bethlehem Institute of Engineering, Indiaon 19 November 2020
52	Delivered a talk in Faculty Development program on " Smart materials and sensors: Current updates and future perspective " organized by Stella mary's college of Engineering and Technology, India on 11 th July 2020
51	Keynote address on "Electronic Devices to Circuits systems" inInternational conference on Electronic and Sustainable communication systems held Hindusthan Institute of Technology and sciences, India 2 nd , July 2020.
50	Delivered a talk in webinar on "Nanoelectronics and its trending applications" organized by Galgotias University, Delhi on 22th June 2020
49	Delivered a talk in webinar on " Current Trending Devices for 5G Communication " organized by Department of ECE, Kumaraguru College of Technology, Coimbatore on 28 th June 2020
48	Resource person in the National level Three Day Online Faculty Development Program "VLSI technology and hardware for AI and ML" in GMR Institute of Technology, Rajam during 25th to 27th May 2020
47	Delivered a talk in Faculty orientation program on " Future perspective in Research Mobilization " on 13 th , January 2020 in KPR Institute of Engineering and Technology
46	Resource person in the Guest lecture on "VLSI and its Applications" on 09 th "January 2020 in Avinashilingam Institute for Home Science and Higher Education for Women.
45	Resource person in AICTE sponsored Short Term training programm and delivered a lecture on " Recent GaN power process for 5G applications " on 20st August 2019 in PSNA College of engineering and Technology.
44	Keynote address on "Silicon based Energy harvesting devices" inInternational conference on communication and electronic systems held PPG institute of Technology, India 17 th , July 2019.
43	Delivered a talk in Faculty development program on "Bio medical solutions: Integrating new chips, Packages & Modules" held in Jyothi Engineering college, Kerala, India on 10 th July 2019.
42	Resource person in AICTE Sponsored Two week faculty development program and delivered a talk on "Wearable and implantable Technologies" held in VimalJyothi Engineering college, Kerala, India on 25 th May 2019.
41	Keynote address on "Nanogenerators for energy harvesting applications" in International conference on Intelligent computing and control systems held Vaigai College of Engineering, India 15 th , May 2018.
40	Delivered a technical talk on " Semicondcutor Devices and its recent trends " in IEEE Madras section symposium held in Sri Ramakrishna Engineering College, Coimbatore on 25 th January 2018
39	Keynote address on "Semiconductor devices and its applications" in 3 rd IEEE International conference on Inventive systems and control held in JCT College of Engineering and Technology, India 11 th , January 2018.
38	Guest Speaker on " Current Trends in Semicondcutor Devices " in Francis Xavier Engineering College, Tirunelveli on 10 th January 2018
37	Keynote address on "Electronic system design and its reliability issues" in " 3 rd IEEE International conference on Communication and Electronic systems held in PPG Institute of Technology, India 15 th and 16 th , October 2018.
36	Delivered Guest Lecture on " Technology node beyond 14nm in VLSI Systems " in Vellor Institute of Technology, Vellore on 19 th September 2018.
35	Keynote address on "InP based HEMT and its frequency applications" in IEEE Sponsored International conference on Inventive research in computing applications Organized by RVS technical campus coimbatore, India on 2 nd July 2018.
34	Guest Lecture on " Emerging semiconductor devices and its applications " in ShaheedRajguru college of applied sciences for women, University of Delhi , Delhi on 4 th

	April 2018.
33	Speech Delivered on "Flexible electronics and future systems" in Institution of Engineers(India), Coimbatore chapter, Coimbatore on 12 th February 2018.
32	Keynote address on "Flexible semiconductor devices and its applications in future" in IEEE Sponsored 2 nd International conference on Inventive systems and control held in JCT College of Engineering and Technology, India 19 th , January 2018.
31	Guest Lecture on "Recent Advancements in Electronics and Research opportunities in semiconductor devices" in Kumarguru college of Technology, Coimbatore on 22 nd November 2017.
30	Keynote address on "Impact of High Electron Mobility Transistor in MMIC Systems" in IEEE Sponsored 2 nd International conference on Communication and Electronic systems held in PPG Institute of Technology, India 19 th , October 2017
29	Resource person in the CSIR sponsored National seminar and delivered a lecture on "Analysis of Carbon Nanotube and GrapheneNanoribbon Field Effect Transistors" on 21st August 2017 in Karpgam college of engineering.
28	Keynote address on "Current Trends in Junctionless Transistors for Ultra Low power Applications" in IEEE Sponsored International conference on Inventive systems and Control Organized by JCT College of Engineering and technology, India on 19 th January 2017.
27	Delivered a Talk on "Semiconductor Devices and Applications" in One day IEEE ED Coimbatore Chapter sponsored workshop " 2ndNational Workshop on Semiconductor device modeling and applications" in Karunya University, 11th January 2017.
26	Guest Lecture on "NPN and PNP Junctions" in FDTP ON Electron Devices organized by Karpagam Institute of Technology, Coimbatore on 23 th December 2016.
25	Invited talk on "Semiconductor Nano Electronic Devices and its applications for Future Electronics" in National seminar on MEMS and Nano Electronic Devices held on 19 th and 20 th December 2016 in Bharathiar University, India
24	Delivered a Keynote address on "NanoscaleJunctionless Transistor Design and Its Applications" in the IEEE International Conference on Communication and Electronics Systems(ICCES 2016) Organized by PPG Institute of Technology - Coimbatore, India on 21st October 2016.
23	Resource person in the TEQIP-II sponsored faculty development program on "Multiscale modelling and simulation of Nanoelectronic Devices- A research Perspective" on 28th July 2016 in PSG college of Technology.
22	Delivered a Keynote address on "GaN based High Electron Mobility Transistor (HEMT): Trends and applications" in the IEEE sponsored International conference on Electronics and Communication Systems Organized by Karpagam College of Engineering, India on 25 th February 2016.
21	Resource person for a seminar on " Research paper writing: Methodology & Aspect " held on 17 th February, organized by Department of Electronics and communication Engg ECHO association, Karunya University.
20	Delivered a Keynote address on "Emerging trends in Nanotechnology and Integrated circuits" in National Level Workshop on Recent trends of Nanotechnology in Electronics held at Arasu Engineering College, India on 8 th February 2016.
19	Delivered a Technical Talk on "Introduction to High Power & Low Power Devices in Nanotechnology " in Alva's Institute of Engineering and Technology, India on 06 th November 2015.
18	Resource person for IEEE EDS Coimbatore chapter sponsored workshop on "National Semiconductor device modeling and applications" in Karunya University, 9 th October 2015.
17	Delivered a lecture on "VLSI Technologies and research Trends " in Royal college of Engineering and technology, India on 14 th August 2015.

16	Keynote address in the "International conference on Systems, Science, Control, Communication, Engineering and Technology" on Next Generation Electronics and its Applications Organized by Karpagam Institute of Technology, India on 10 th August 2015.
15	Keynote address in the "International conference on Networks, Electronics, Communication and Control" on Heterostructure based MOSFETs in Nano electronic Regime Organized by Cape Institute of Technology, India on 5 th and 6 th March 2015.
14	Keynote address in the "IEEE 9 th International conference on Intelligent Systems and Control" On Advanced high power semiconductor devices and its application Organized by Karpagam college of Engineering, India on 9 th and 10 th January 2015.
13	Delivered a plenary talk in the IEEESSCS Sponsored Conference On "Solid State Circuits" Organized by SaintGits college of Engineering, India on 29 th August 2014.
12	Resource person for IEEE India EDS chapter sponsored workshop on "Nano Electronics Device Modelling " in Mahendra Engineering College on 14 th July 2014.
11	Delivered a Talk on "Nano electronics in recent trends " in RevaITM,Bangalore India on 24 th March 2014.
10	Delivered a Special Guest lecture on "VLSI Design " in Pavai College of Technology, India on 28 th January 2014.
9	Delivered a Guest lecture in IETE Student forum inauguration on "Nano electronics in Communication systems" in Karpagam college of Engineering, India on 30 th September 2013.
8	Delivered a special lecture in One day seminar on "Advanced Research Methodologies in VLSI System" in Cape Institute of Technology, India on 12 th August 2013.
7	Delivered a Keynote Talk in 2013 IEEE International Conference on Emerging Trends in Computing, Communication and Nanotechnology Organized by Infant Jesus College of Engineering, India on 25 th and 26 th March 2013.
6	Resource person in " Workshop for Writing Journal Papers " at Karunya University, Coimbatore on 6 th March 2013.
5	Guest Lecture on " Emerging Trends in Nano Electronics for VLSI Applications " in Paavai College Of Engineering, Namakkal on 12 th February 2013.
4	Technical Talk On "Emerging Engineering Technologies Using FinFETwith High-K Dielectrics" in the IEEE INDIA EDS chapter workshop on FinFET Circuit Design-An Alternate for CMOS Design conducted in Muthayammal Engineering College, Rasispuram, India 2012.
3	Guest lecture in National workshop on " Low power VLSI methodologies " organized by Hindustan Institute of Technology, Coimbatore conducted on 24 th April 2010.
2	Resource person for National Workshop "Find your way with Wonder Chip: VLSI" organized by Karunya University conducted from 19 th of September 2009 to 21 st of September 2009.
1	Delivered an Invited lecture on the topic "INTRODUCTION TO SYNOPSYS" in Karunya University.

INTERNATIONAL COURSES / SEMINARS ATTENDED

16	Participated in the Webinar on "Pedagogy of Online Teaching and Assessment", 10th August, 2020 organized by the Department of Electrical and Electronics Engineering, PSG College of Technology, Coimbatore in association with The Institution of Engineers (India), Coimbatore local center.
15	Attended online FDP on Patent Law for Engineers and Researchers conducted by AICTE ATAL from 26-30 July 2020 at Prathyusha Engineering College
14	Attended online FDP on Sensors Technology conducted by AICTE ATAL from 21-25 September 2020 at Dr. Ambedkar Institute of Technology,

13	Attended online FDP on Internet of Things conducted by AICTE ATAL from 07-11 December 2020 at Indian Institute of Information Technology, Kottayam.
12	Attended online FDP on Photonics conducted by AICTE ATAL from 01-05 February 2021 at National Institue of Technolgy
11	Participated in Indian Technology Congress – 2019 on 4 th & 5 th September 2019 at NIMHANS Convention Centre, Bengaluru.
10	Attended Five day International Faculty development programm on "Exploring the Nuances of Deep learning for research applications- A Deeper Experience" held on 13 th to 17 th July 2020 Karunya Institute of Technology and sciences, India.
9	Participated in IEEE EDS Distinguished Lecture on "Transparent and flexible large area electronics" Organized by IEEE EDS Delhi chapter in association with University of Delhi South Campus on 16 th May 2020.
8	Participated in IEEE EDS Distinguished Lecture on "Theory of Nano- Electron- Fluidic Logic(NFL): A New Digital Electronics concept " Organized by IEEE EDS Coimbatore chapter in association with ECE, Karunya institute of technology and sciences on 5 th December 2017.
7	Participated in the workshop on "Nanolithography and Nanofabrication" Organized by Raith India and Raith GmbH Germany, held in Indian Institute of Science, Bangalore on 16th Many 2017.
6	Participated in "IEEE Sponsored International conference on Innovations in Electrical ,Electronics, Instrumentation and Media Technology" held in Karunya University, India on 3 rd and 4 th , February 2017.
5	Completed the course on "Crosscheck for conferences- Plagiarism Detection Tool" from IEEE on September 1 st 2016.
4	Participated in the IEEE Volunteer Leadership Training programme (VOLT) Program Graduate 2015.
3	Participated in pre-conference workshop in "International Conference on signal processing, Image processing and pattern Recognition" on Lab View held on 6 th February 2013 at Karunya University.
2	Attended the International workshop and IEEE EDS Mini-colloquia on "The past & future of Integrated Circuits Technologies" held during November 4-5, 2009 at S.K.P Engineering college, Tiruvannamalai.
1	Advanced International Workshop on "NANOSCIENCE AND TECHNOLOGY" Organized by Anna University Chennai on 2009.

NATIONAL COURSES / SEMINARS ATTENDED

29	Participated in the online IP awareness and Training program conducted by Intellectual Propery India on 12 February 2022
28	Attended a Webinar on "Quantum dot cellular automata: Emerging Technology for Nano architecture" held on 20thJuly 2020 in Sri Eshwar college of Engineering India.
27	Attended a Webinar on "Intellectual Property Rights and Patent Filing" held on 22 nd May 2020 Aurora's Degree & PG College, Chikkadpally, Hyderabad, India.
26	Attended a Leadership talk byMHRDInnovaion Cell held on 16 th May 2020 in Government Of India.
25	Attended a Webinar on "Selection of appropriate Statistical Tools: A critical way for successful Research" held on 12th May 2020 in St Mary's College, Thoothukudi, India.
24	Attended a Webinar on "Research Methodology and its tools" held on 12 th May 2020 in Crescent Institute of Technology and sciences India.
23	Attended a Webinar on "Machine learning algorithms, applications and trends" held on 10 th May 2020 in Shri ShankarlalSundarbaiShasun Jain college for women association

Participated an Training programme on "Question paper setting" held on 30th May to 1st June 2018 in Karunya Institute of technology and sciences conducted by National Institute of Technical Teachers Training and research (MRIRD, 60 of India). Attended "One day Joint workshop on Patent Filing Procedure" on 7th June 2018 Organized by Rajiv Gandhi National Institute of Intellectual Property Management, Nagpur and Karunya Institute of technology and sciences. Participated a One day workshop on "Intellectual property Rights Regime in India-IPRP1" held on 18th September 2017 in Karunya University, India. Participated in National workshop on "Applications of Graph theory in Engineering" held on 28th April 2016 in Karunya University, India. Participated in "National seminar on MEMS and Nano Electronic Devices 2016" held on 18th 29th 2016 in Bharathiar University, India. Attended faculty development workshop on "Effective teaching Learning Methodology for Engineers" Organized by Department of Electrical Technology, Karunya University on 23th Jun 2016 Attended one day National level conclave on IOT for smart city on 16th April 2016 in karunya university. Participated in "Virtual Labs Workshops" conducted at Karunya University on 20th Erbruary 2016. Attended one day workshop on "Intellectual Property Rights" on 15th September, 2016 in Karunya University. Attended a faculty development program on "Team building and Leadership skill" Organized by Dept. of ECE Karunya University on 6th September 2014. Attended a faculty development program on "Team building and Leadership skill" Organized by Dept. of ECE Karunya University on february 14, 2014. Attended the one day Workshop on Project Proposal Writing" in Karunya University, Coimbatore, February 13th 2013. Attended the one day training program in center for VLSI & Nanotechnology in S.K.P Engineering College, Tiruvannamalai, 24 September 2010. Attended the one day training program in center for VLSI & Nanotechnology in S.K.P Engineering College, Tiruvannamalai, 2		with Computer society of India.
21 Organized by Rajiv Gandhi National Institute of Intellectual Property Management, Nagpur and Karunya Institute of technology and sciences. 20 Participated a One day workshop on "Intellectual property Rights Regime in India-1PRP17" held on 18th September 2017 in Karunya University, India. 19 Participated in National workshop on "Applications of Graph theory in Engineering" held on 28th April 2016 in Karunya University, India. 18 Participated in "National seminar on MEMS and Nano Electronic Devices 2016" held on 19th and 20th December 2016 in Bharathiar University, India. Attended faculty development workshop on "Effective teaching Learning Methodology for Engineers" Organized by Department of Electrical Technology, Karunya University on 23th Jun 2016 Attended one day National level conclave on IOT for smart city on 16th April 2016 in karunya university. Participated in "Virtual Labs Workshops" conducted at Karunya University on 20th February 2016. Attended one day workshop on "Intellectual Property Rights" on 15th September, 2016 in Karunya University. Attended a faculty development program on "Team building and Leadership skill" Organized by Dept. of ECE Karunya University on 6th September 2014. Attended a workshop on "OMSOLMultiphysics Modeling" organized by Electronics and Instrumentation Engineering Department, Karunya University on February 14th 2013. Attended the one day "Workshop on Project Proposal Writing" in Karunya University, Coimbatore, February 13th 2013. Attended the one day training program in center for VLSI & Nanotechnology in S.K.P Engineering College, Trivvannamalai, 24 September 2010. Attended the One day training program in center for VLSI & Nanotechnology in S.K.P Engineering College, Trivvannamalai, 24 September 2010. Attended the One day Hands-on-training program on "VLSI Back-end tools" organized by Kumaraguru college of Technologies, IISC, Bangalore, 15-16 April 2010. Attended the One day Hands-on-training program on "VLSI Back-end tools" organized by Kumarasity oluniv	22	Participated an Training programme on "Question paper setting" held on 30 th May to 1 st June 2018 in Karunya Institute of technology and sciences conducted by National Institute
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